



VS-GB200TH120U Information

Heisener.com

Part Number VS-GB200TH120U

Manufacturer Vishay Semiconductor Diodes Division

Category Discrete Semiconductor Products

Transistors - IGBTs - Modules

Description IGBT 1200V 330A 1316W INT-A-PAK

Package Double INT-A-PAK (3 + 4)

For the pricing/inventory/lead time, please contact

us

For Reference Only

Website: https://www.heisener.com

E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









VS-GB200TH120U Specifications

Manufacturer Part Number	VS-GB200TH120U
Manufacturer	Vishay Semiconductor Diodes Division
Category	Discrete Semiconductor Products
	Transistors - IGBTs - Modules
Package	Double INT-A-PAK (3 + 4)
Series	-
IGBT Type	-
Configuration	Half Bridge
Voltage - Collector Emitter Breakdown (Max)	1200V
Current - Collector (Ic) (Max)	330A
Power - Max	1316W
Vce(on) (Max) @ Vge, Ic	3.6V @ 15V, 200A
Current - Collector Cutoff (Max)	5mA
Input Capacitance (Cies) @ Vce	16.9nF @ 30V
Input	Standard
NTC Thermistor	No
Operating Temperature	150°C (TJ)
Mounting Type	Chassis Mount
Package / Case	Double INT-A-PAK (3 + 4)
Supplier Device Package	Double INT-A-PAK
	Report errors?

VS-GB200TH120U Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

VS-GB200TH120U Payment Methods





















VS-GB200TH120U Shipping Methods













If you have any question about VS-GB200TH120U, please do not hesitate to contact us!

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